Vishay Semiconductors

High Performance Schottky Rectifier, 1.0 A



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Cathode o	Anode o	

PRODUCT SUMMARY		
Package	SMB	
I _{F(AV)}	1.0 A	
V _R	30 V	
V _F at I _F	0.30 V	
I _{RM} max.	20 mA at 125 °C	
T _J max.	125 °C	
Diode variation	Single die	
E _{AS}	3.0 mJ	

FEATURES

- · Small foot print, surface mountable
- · Very low forward voltage drop
- High frequency operation



COMPLIANT

- HALOGEN · Guard ring for enhanced ruggedness and long FREE term reliability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

DESCRIPTION

The VS-MBRS130L-M3 surface mount Schottky rectifier has been designed for applications requiring low forward drop and small foot prints on PC boards. Typical applications are in disk drives, switching power supplies, converters, freewheeling diodes, battery charging, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS				
SYMBOL	CHARACTERISTICS	VALUES	UNITS	
I _{F(AV)}	Rectangular waveform	1.0	A	
V _{RRM}		30	V	
I _{FSM}	t _p = 5 μs sine	230	A	
VF	1.0 A _{pk} , T _J = 125 °C	0.30	V	
TJ	Range	-55 to +125	°C	

VOLTAGE RATINGS			
PARAMETER	SYMBOL	VS-MBRS130L-M3	UNITS
Maximum DC reverse voltage	V _R	30	V
Maximum working peak reverse voltage	V _{RWM}	50	v

ABSOLUTE MAXIMUM RATINGS					
PARAMETER	SYMBOL	TEST CONDI	TIONS	VALUES	UNITS
Maximum average forward current	I _{F(AV)}	50 % duty cycle at T _L = 112 °C, rectangular waveform		1.0	
Maximum peak one cycle		5 µs sine or 3 µs rect. pulse	Following any rated load condition and with rated	230	А
non-repetitive surge current	IFSM	10 ms sine or 6 ms rect. pulse	V_{RRM} applied	40	
Non-repetitive avalanche energy	E _{AS}	T _J = 25 °C, I _{AS} = 1 A, L = 6 mH		3.0	mJ
Repetitive avalanche current	I _{AR}	$\begin{tabular}{lllllllllllllllllllllllllllllllllll$		А	

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EI	ECTD	SPECIFICATIONS
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ELECTRICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maria and tables door		1 A	T,I = 25 °C	0.420	V
	V _{FM} ⁽¹⁾	2 A	1j=23 0	0.470	
Maximum forward voltage drop	VFM (*)	1 A	T ₁ = 125 °C	0.300	
		2 A	$1_{\rm J} = 125$ C	0.370	
		T _J = 25 °C		1	
Maximum reverse leakage current I _{RM} ⁽¹⁾	T _J = 100 °C	$V_R = Rated V_R$	10	mA	
		T _J = 125 °C		20	
Maximum junction capacitance	CT	$V_R = 5 V_{DC}$ (test signal range 100 kHz to 1 MHz), 25 °C		200	pF
Typical series inductance	L _S	Measured lead to lead 5 mm from package body 2.0		2.0	nH
Maximum voltage rate of change	dV/dt	Rated V _R 10 000 V/µs		V/µs	

Note

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 $^{(1)}\,$ Pulse width < 300 $\mu s,$ duty cycle < 2 $\,\%$

THERMAL - MECHANICAL SPECIFICATIONS				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction temperature range	T _J ⁽¹⁾		-55 to +125	°C
Maximum storage temperature range	T _{Stg}		-55 to +150	C
Maximum thermal resistance, junction to lead	R _{thJL} ⁽²⁾	DC operation See fig. 4	25	°C/W
Maximum thermal resistance, junction to ambient	R _{thJA}	DC operation	80	0/11
Approvimete weight			0.10	g
Approximate weight			0.003	oz.
Marking device		Case style SMB (similar to DO-214AA)	13	L

Notes

 $\frac{dP_{tot}}{dT_J} < \frac{1}{R_{thJA}}$ thermal runaway condition for a diode on its own heatsink (1)

(2) Mounted 1" square PCB



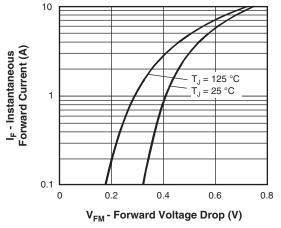


Fig. 1 - Maximum Forward Voltage Drop Characteristics

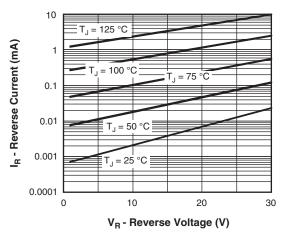
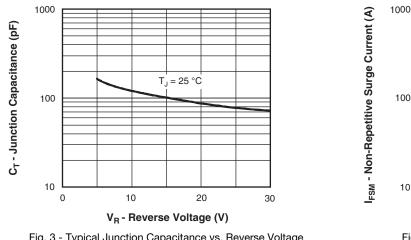
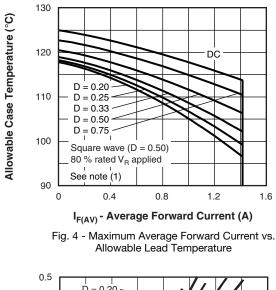


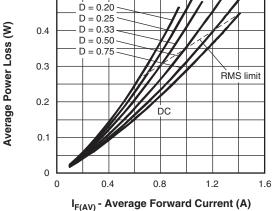
Fig. 2 - Typical Peak Reverse Current vs. Reverse Voltage





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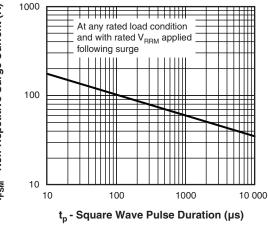


Fig. 6 - Maximum Peak Surge Forward Current vs. Pulse Duration

Note

⁽¹⁾ Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$;

Pd = Forward power loss = I_{F(AV)} x V_{FM} at (I_{F(AV)}/D) (see fig. 6); Pd_{REV} = Inverse power loss = V_{R1} x I_R (1 - D); I_R at V_{R1} = 80 % rated V_R

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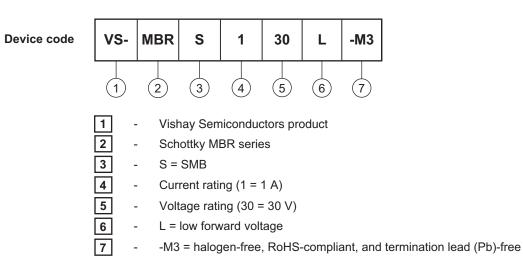
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ISHA



ORDERING INFORMATION (Example)				
PREFERRED P/N	PREFERRED PACKAGE CODE	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION	
VS-MBRS130L-M3/5BT	5BT	3200	13" diameter plastic tape and reel	

LINKS TO RELATED DOCUMENTS		
Dimensions www.vishay.com/doc?95401		
Part marking information	www.vishay.com/doc?95403	
Packaging information	www.vishay.com/doc?95404	

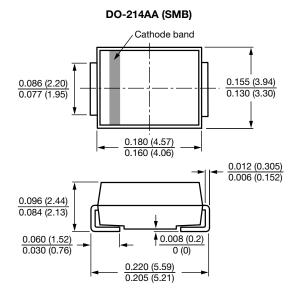


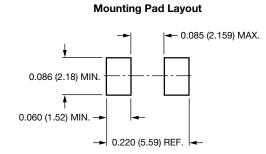
Outline Dimensions

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SMB

DIMENSIONS in inches (millimeters)







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